



20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

-7.2A

Features

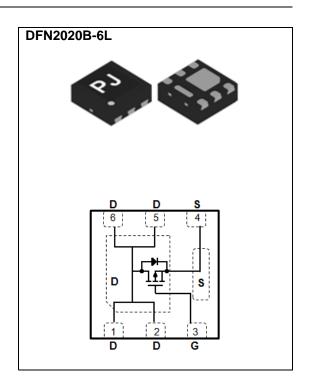
- RDS(ON), VGS@-4.5V, ID@-7.2A<32mΩ
- RDS(ON), VGS@-2.5V, ID@-5.0A<39mΩ
- RDS(ON), VGS@-1.8V, ID@-2.5A<48mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN2020B-6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0086 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAME	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	-7.2	Α
Pulsed Drain Current		I _{DM}	-28.8	Α
Power Dissipation	T _a =25°C	P _D	2.8	W
	Derate above 25°C		22	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient, t<10s (Note 3)		R _θ ЈА	44.6	°C/W





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-0.35	-0.6	-0.9	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V,I _D =-7.2A	-	25	32	mΩ
		V _{GS} =-2.5V,I _D =-5.0A	-	30	39	
		V _{GS} =-1.8V,I _D =-2.5A	-	35	48	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V,V _{GS} =0V	-	-0.01	-1.0	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =-10V, I _D =-7.2A, V _{GS} =-4.5V (Note 1,2)	-	18.9	-	nC
Gate-Source Charge	Q_gs		-	2.8	-	
Gate-Drain Charge	Q_gd		-	4.2	-	
Input Capacitance	Ciss	101/11/01/	-	1785	-	pF
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	152	-	
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	125	-	
Turn-On Delay Time	td _(on)	1/ 40\/ 1 704	-	12	-	
Turn-On Rise Time	tr	V _{DS} =-10V, I _D =-7.2A, V _{GEN} =-4.5V, R _L =10Ω	-	68	-	ns
Turn-Off Delay Time	td _(off)		-	82	-	
Turn-Off Fall Time	tf	R _G =6Ω (Note 1,2)	-	35	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				-	-1.5	А
Diode Forward Current	ls					
Diode Forward Voltage	V_{SD}	Is=-1A, V _G s=0V	-	-0.64	-1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

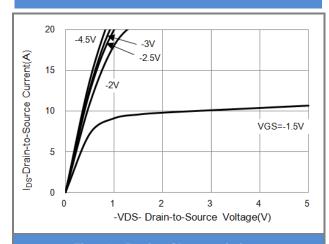


Fig.1 On-Region Characteristics

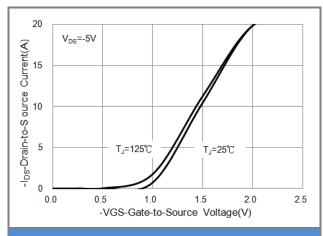


Fig.2 Transfer Characteristics

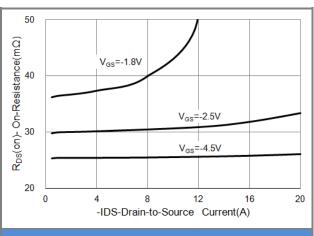


Fig.3 On-Resistance vs. Drain Current

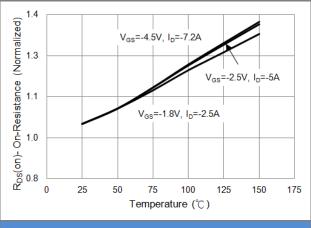


Fig.4 On-Resistance vs. Junction temperature

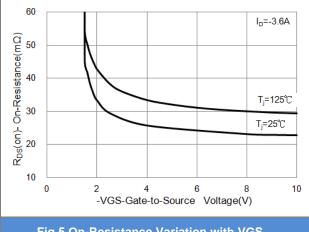
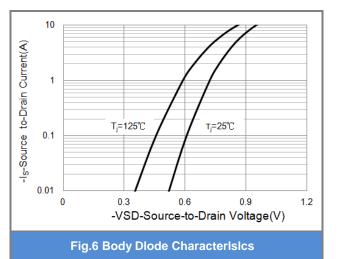


Fig.5 On-Resistance Variation with VGS.







TYPICAL CHARACTERISTIC CURVES

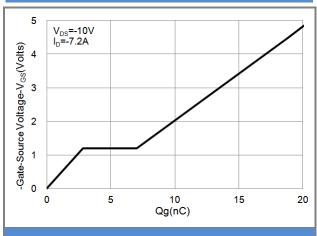


Fig.7 Gate-Charge Characteristics

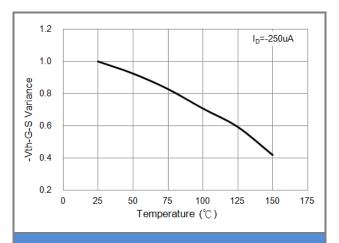


Fig.8 Threshold Voltage Variation with Temperature.

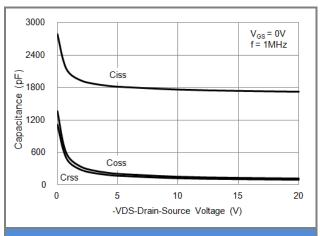


Fig.9 Capacitance vs. Drain-Source Voltage.

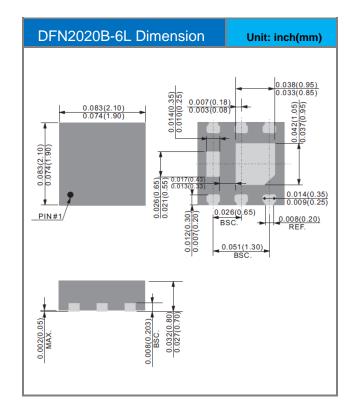


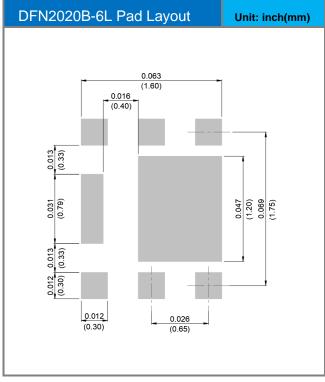


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2405_R1_00001	DFN2020B-6L	3K pcs / 7" reel	405	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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